CSD95472Q5MC 同步降压 NexFET™智能功率级

1 特性

- 60A 持续运行电流能力
- 1.2V/30A 下系统效率达 94.4%
- 30A 电流下功率损耗低至 2.3W
- 高频工作（高达 1.25MHz）
- 支持强制连续传导模式 (FCCM) 的二极管仿真模式
- 温度补偿双向电流感测
- 模拟温度输出（0°C 时 600mV）
- 故障监控
  - 高端短路、过流和过热保护
- 3.3V 和 5V 脉宽调制 (PWM) 信号兼容
- 三态 PWM 输入
- 集成型自举二极管
- 优化了击穿保护死区时间
- 高密度小外形尺寸无引线 (SON) 5mm x 6mm 封装
- 超低电感封装
- 系统优化的 PCB 封装
- DualCool™封装
- 符合 RoHS 标准 - 无铅引脚镀层
- 无卤素

2 应用

- 多相位同步降压转换器
  - 高频 应用
  - 高电流、低占空比 应用
- 负载点 (POL) 直流 - 直流转换器
- 内存和图形卡

3 说明

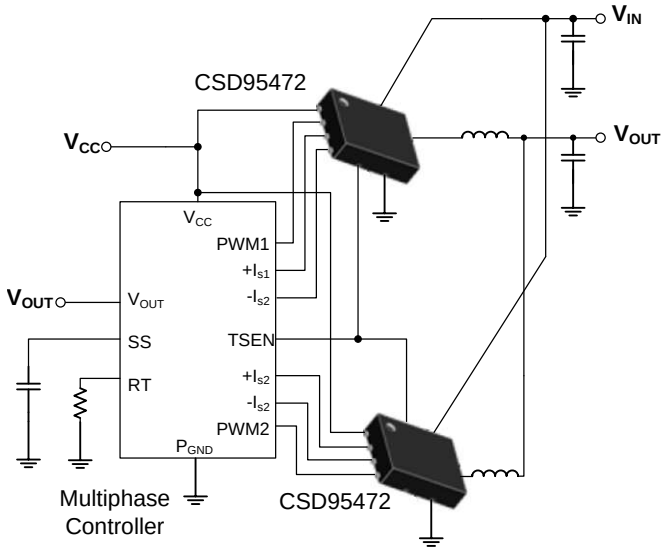
CSD95472Q5MC NexFET™智能功率级的设计针对高功率、高密度同步降压转换器中的使用进行了高度优化。这个产品集成了驱动器集成电路 (IC) 和功率金属氧化物半导体场效应晶体管 (MOSFET) 来完善功率级开关功能。这个组合在小型 5mm x 6mm 外形尺寸封装中产生出高电流、高效和高速切换功能。它还集成了准确电流感测和温度感测功能，以简化系统设计并提高准确度。此外，已对 PCB 封装进行了优化以帮助减少设计时间并简化总体系统设计的完成。

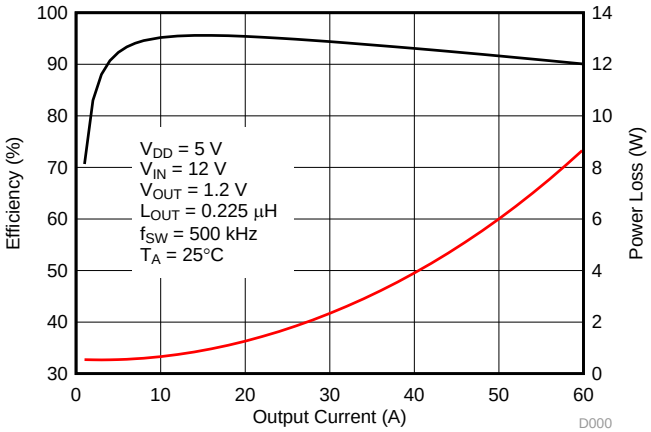
器件信息(1)

器件	包装介质	数量	封装	运输
CSD95472Q5MC	13 英寸卷带	2500	SON 5 × 6mm DualCool 封装	卷带封装
CSD95472Q5MCT	7 英寸卷带	250		

(1) 要了解所有可用封装，请见数据表末尾的可订购产品附录。

应用图表





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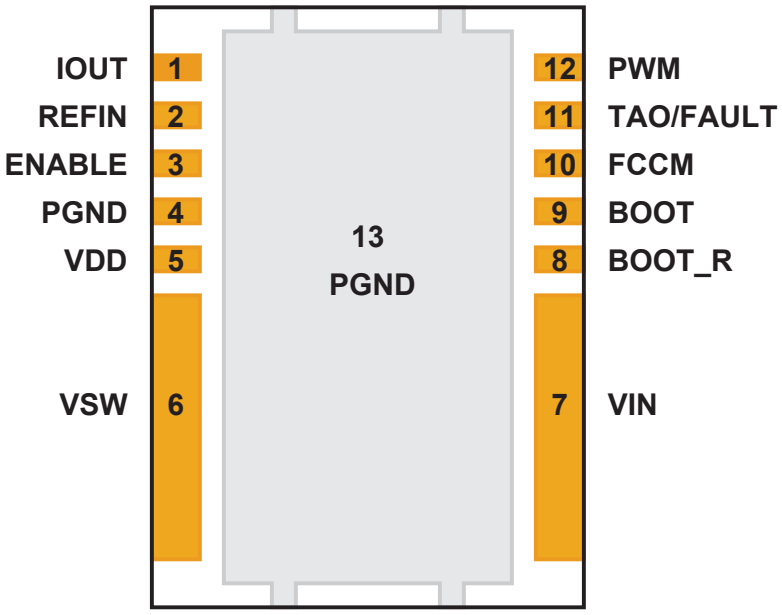
4 修订历史记录

日期	修订版本	注释
2 月 2016	*	最初发布。

5 Pin Configuration and Functions

Top View



Pin Functions

PIN		DESCRIPTION
NUMBER	NAME	
1	IOUT	Output of current sensing amplifier. V(IOUT) – V(REFIN) is proportional to the phase current.
2	REFIN	External reference voltage input for current sensing amplifier.
3	ENABLE	Enables device operation. If ENABLE = logic HIGH, turns on device. If ENABLE = logic LOW, the device is turned off and both MOSFET gates are actively pulled low. An internal 100 kΩ pulldown resistor will pull the ENABLE pin LOW if left floating.
4	P_{GND}	Power ground, connected directly to pin 13.
5	V_{DD}	Supply voltage to gate driver and internal circuitry.
6	V_{SW}	Phase node connecting the HS MOSFET source and LS MOSFET drain – pin connection to the output inductor.
7	V_{IN}	Input voltage pin. Connect input capacitors close to this pin.
8	BOOT_R	Return path for HS gate driver, connected to V_{SW} internally.
9	BOOT	Bootstrap capacitor connection. Connect a minimum of 0.1 µF 16 V X7R ceramic capacitor from BOOT to BOOT_R pins. The bootstrap capacitor provides the charge to turn on the control FET. The bootstrap diode is integrated.
10	FCCM	This pin enables the diode emulation function. When this pin is held LOW, diode emulation mode is enabled for sync FET. When FCCM is HIGH, the device is operated in forced continuous conduction mode. An internal 5 µA current source will pull the FCCM pin to 3.3 V if left floating.
11	TAO/ FAULT	Temperature Analog Output. Reports a voltage proportional to the die temperature. An ORing diode is integrated in the IC. When used in multiphase application, a single wire can be used to connect the TAO pins of all the ICs. Only the highest temperature will be reported. TAO will be pulled up to 3.3 V if thermal shutdown occurs. TAO should be bypassed to P_{GND} with a 1 nF 16 V X7R ceramic capacitor.
12	PWM	Pulse width modulated tri-state input from external controller. Logic LOW sets control FET gate low and sync FET gate high. Logic HIGH sets control FET gate high and sync FET gate low. Open or High Z sets both MOSFET gates low if greater than the tri-state shutdown hold-off time (t_{3HT}).
13	P_{GND}	Power ground.

6 Specifications

6.1 Absolute Maximum Ratings

T_A = 25°C (unless otherwise noted)(1)

		MIN	MAX	UNIT
	V_{IN} to P_{GND}	–0.3	20	V
	V_{IN} to V_{SW}	–0.3	20	V
	V_{IN} to V_{SW} (10 ns)		23	V
	V_{SW} to P_{GND}	–0.3	20	V
	V_{SW} to P_{GND} (10 ns)	–7	23	V
	V_{DD} to P_{GND}	–0.3	7	V
	ENABLE, PWM, FCCM, TAO, IOUT, REFIN to P_{GND}(2)	–0.3	V_{DD} + 0.3 V	V
	BOOT to BOOT_R(2)	–0.3	V_{DD} + 0.3 V	V
P_D	Power dissipation		12	W
T_J	Operating junction	–55	150	°C
T_{stg}	Storage temperature	–55	150	

(1) Stresses beyond those listed under *Absolute Maximum Ratings* may cause permanent damage to the device. These are stress ratings only, which do not imply functional operation of the device at these or any other conditions beyond those indicated under *Recommended Operating Conditions*. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.
(2) Should not exceed 7 V.

6.2 ESD Ratings

			VALUE	UNIT
$V_{(ESD)}$	Electrostatic discharge	Human body model (HBM)	±2000	V
		Charged device model (CDM)	±500	

6.3 Recommended Operating Conditions

T_A = 25° (unless otherwise noted)

			MIN	MAX	UNIT
V_{DD}	Gate drive voltage		4.5	5.5	V
V_{IN}	Input supply voltage(1)			16	V
V_{OUT}	Output voltage			5.5	V
I_{OUT}	Continuous output current	V_{IN} = 12 V, V_{DD} = 5 V, V_{OUT} = 1.2 V, f_{SW} = 500 kHz, L_{OUT} = 0.225 µH(2)		60	A
I_{OUT-PK}	Peak output current(3)			90	A
f_{SW}	Switching frequency	C_{BST} = 0.1 µF (min)		1250	kHz
	On time duty cycle	f_{SW} = 1 MHz		85%	
	Minimum PWM on time		40		ns
	Operating temperature		–40	125	°C

(1) Operating at high V_{IN} can create excessive AC voltage overshoots on the switch node (V_{SW}) during MOSFET switching transients. For reliable operation, the switch node (V_{SW}) to ground voltage must remain at or below the *Absolute Maximum Ratings*.
(2) Measurement made with six 10 µF (TDK C3216X5R1C106KT or equivalent) ceramic capacitors placed across V_{IN} to P_{GND} pins.
(3) System conditions as defined in Note 1. Peak Output Current is applied for t_p = 50 µs.

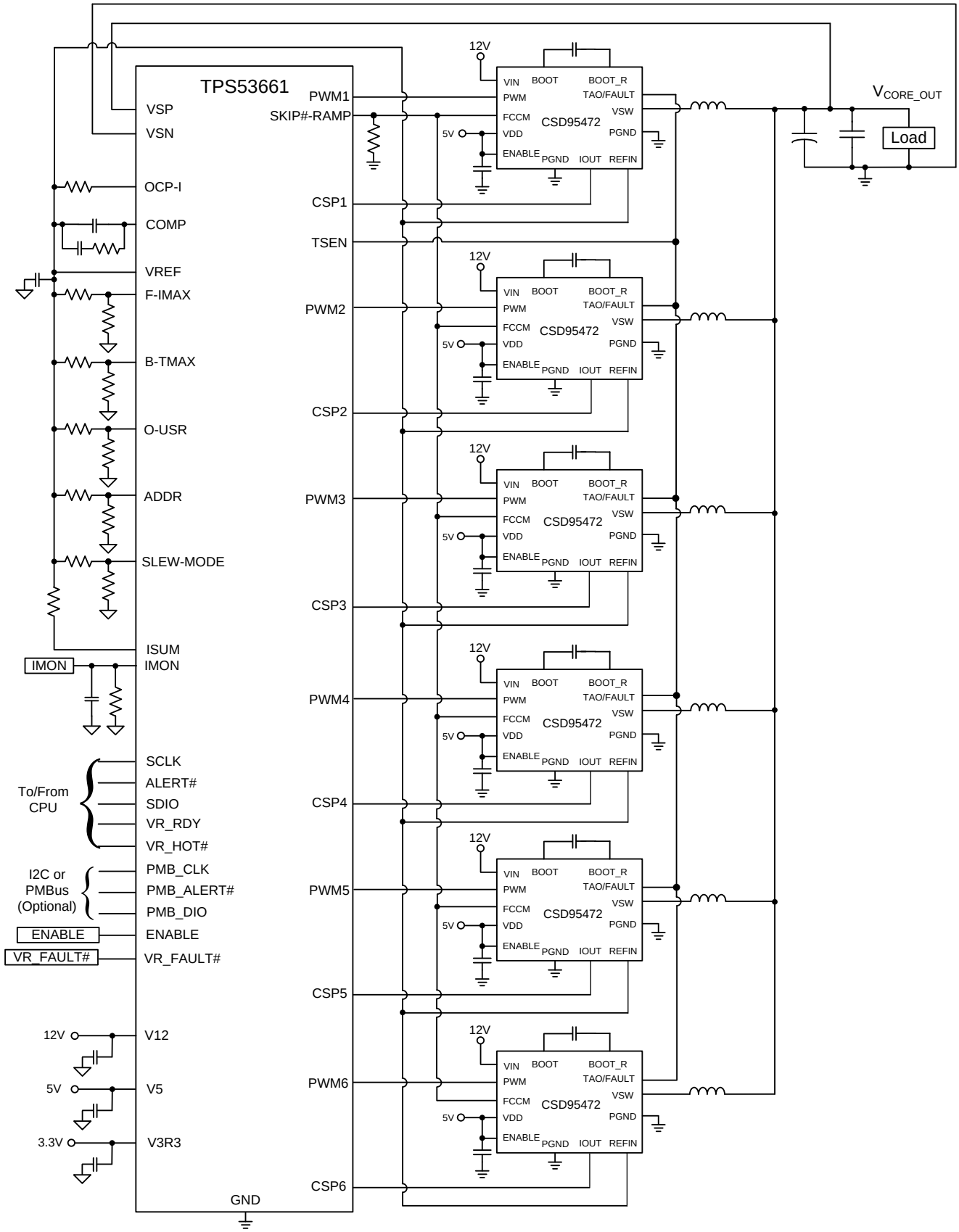
6.4 Thermal Information

T_A = 25°C (unless otherwise noted)

THERMAL METRIC		MIN	TYP	MAX	UNIT
$R_{\theta JC(top)}$	Junction-to-case (top of package) thermal resistance (1)			5	°C/W
$R_{\theta JB}$	Junction-to-board thermal resistance(2)			1.5	

(1) $R_{\theta JC(top)}$ is determined with the device mounted on a 1 inch² (6.45 cm²), 2-oz (0.071 mm thick) Cu pad on a 1.5 inches x 1.5 inches, 0.06-inch (1.52-mm) thick FR4 board.
(2) $R_{\theta JB}$ value based on hottest board temperature within 1 mm of the package.

7 Application Schematic



8 器件和文档支持

8.1 社区资源

The following links connect to TI community resources. Linked contents are provided "AS IS" by the respective contributors. They do not constitute TI specifications and do not necessarily reflect TI's views; see TI's Terms of Use.

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Design Support ***TI's Design Support*** Quickly find helpful E2E forums along with design support tools and contact information for technical support.

8.2 商标

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8.3 静电放电警告

这些装置包含有限的内置 ESD 保护。 存储或装卸时，应将导线一起截短或将装置放置于导电泡棉中，以防止 MOS 门极遭受静电损伤。

8.4 Glossary

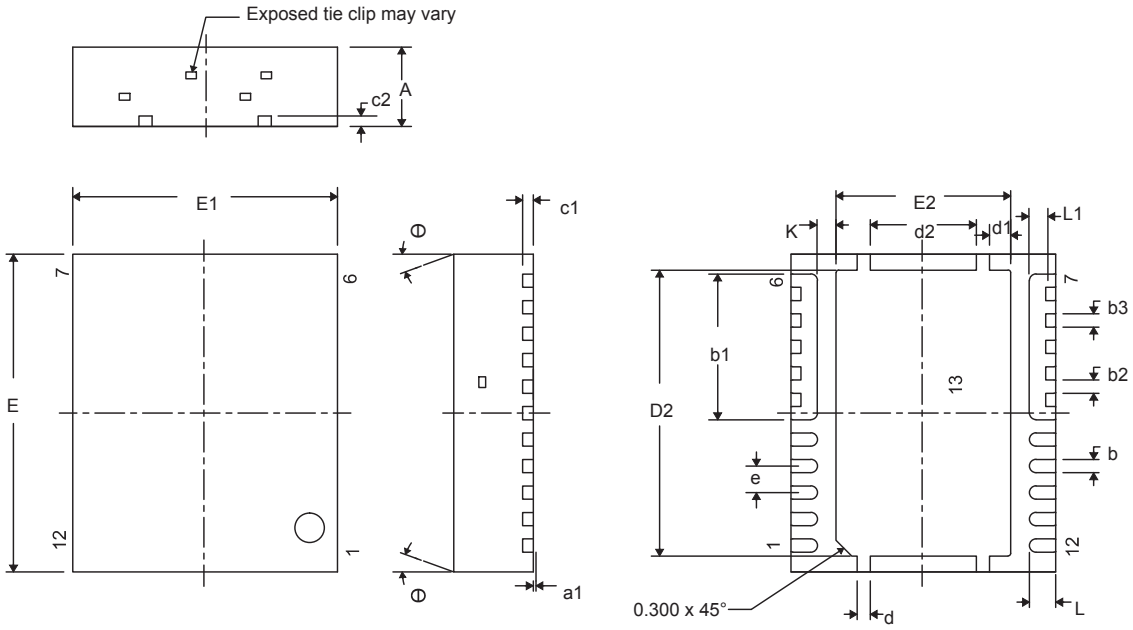
SLYZ022 — *TI Glossary*.

This glossary lists and explains terms, acronyms, and definitions.

9 机械、封装和可订购信息

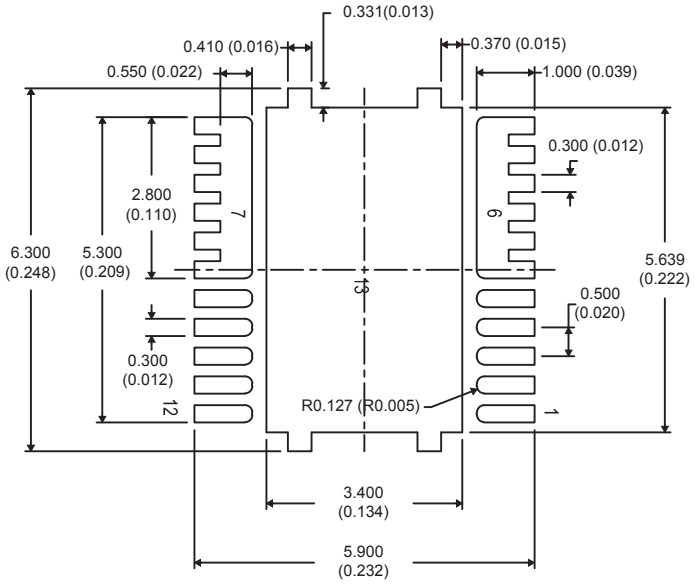
以下页中包括机械、封装和可订购信息。这些信息是针对指定器件可提供的最新数据。这些数据会在无通知且不对本文档进行修订的情况下发生改变。欲获得该数据表的浏览器版本，请查阅左侧的导航栏。

9.1 机械制图



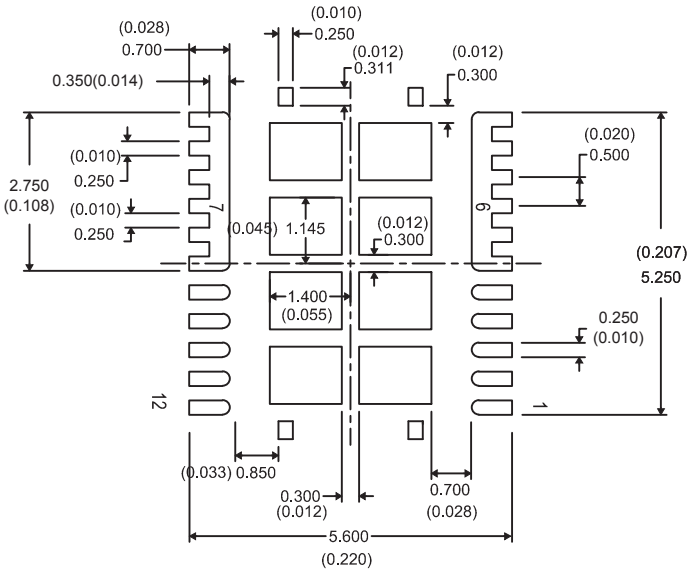
DIM	毫米			英寸		
	最小值	标称值	最大值	最小值	标称值	最大值
A	0.950	1.000	1.050	0.037	0.039	0.041
a1	0.000	0.000	0.050	0.000	0.000	0.002
b	0.200	0.250	0.320	0.008	0.010	0.013
b1		2.750 典型值			0.108 典型值	
b2	0.200	0.250	0.320	0.008	0.010	0.013
b3		0.250 典型值			0.010 典型值	
c1	0.150	0.200	0.250	0.006	0.008	0.010
c2	0.200	0.250	0.300	0.008	0.010	0.012
D2	5.300	5.400	5.500	0.209	0.213	0.217
d	0.200	0.250	0.300	0.008	0.010	0.012
d1	0.350	0.400	0.450	0.014	0.016	0.018
d2	1.900	2.000	2.100	0.075	0.079	0.083
E	5.900	6.000	6.100	0.232	0.236	0.240
E1	4.900	5.000	5.100	0.193	0.197	0.201
E2	3.200	3.300	3.400	0.126	0.130	0.134
e		0.500 典型值			0.020 典型值	
K		0.350 典型值			0.014 典型值	
L	0.400	0.500	0.600	0.016	0.020	0.024
L1	0.210	0.310	0.410	0.008	0.012	0.016
θ	0.00	—	—	0.00	—	—

9.2 建议印刷电路板 (PCB) 焊盘图案



1. 尺寸单位为 mm（英寸）。

9.3 建议模板开口



1. 尺寸单位为 mm（英寸）。
2. 模板厚度为 100µm。

PACKAGING INFORMATION

Orderable part number	Status (1)	Material type (2)	Package | Pins	Package qty | Carrier	RoHS (3)	Lead finish/ Ball material (4)	MSL rating/ Peak reflow (5)	Op temp (°C)	Part marking (6)
CSD95472Q5MC	Active	Production	VSON-CLIP (DMC) | 12	2500 | LARGE T&R	ROHS Exempt	SN	Level-2-260C-1 YEAR	-55 to 150	95472MC
CSD95472Q5MC.A	Active	Production	VSON-CLIP (DMC) | 12	2500 | LARGE T&R	ROHS Exempt	SN	Level-2-260C-1 YEAR	-55 to 150	95472MC
CSD95472Q5MCT	Active	Production	VSON-CLIP (DMC) | 12	250 | SMALL T&R	ROHS Exempt	SN	Level-2-260C-1 YEAR	-55 to 150	95472MC
CSD95472Q5MCT.A	Active	Production	VSON-CLIP (DMC) | 12	250 | SMALL T&R	ROHS Exempt	SN	Level-2-260C-1 YEAR	-55 to 150	95472MC

(1) **Status:** For more details on status, see our product life cycle.

(2) **Material type:** When designated, preproduction parts are prototypes/experimental devices, and are not yet approved or released for full production. Testing and final process, including without limitation quality assurance, reliability performance testing, and/or process qualification, may not yet be complete, and this item is subject to further changes or possible discontinuation. If available for ordering, purchases will be subject to an additional waiver at checkout, and are intended for early internal evaluation purposes only. These items are sold without warranties of any kind.

(3) **RoHS values:** Yes, No, RoHS Exempt. See the TI RoHS Statement for additional information and value definition.

(4) **Lead finish/Ball material:** Parts may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

(5) **MSL rating/Peak reflow:** The moisture sensitivity level ratings and peak solder (reflow) temperatures. In the event that a part has multiple moisture sensitivity ratings, only the lowest level per JEDEC standards is shown. Refer to the shipping label for the actual reflow temperature that will be used to mount the part to the printed circuit board.

(6) **Part marking:** There may be an additional marking, which relates to the logo, the lot trace code information, or the environmental category of the part.

Multiple part markings will be inside parentheses. Only one part marking contained in parentheses and separated by a "~" will appear on a part. If a line is indented then it is a continuation of the previous line and the two combined represent the entire part marking for that device.

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